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# FQU3N50C

## N-Channel QFET® MOSFET

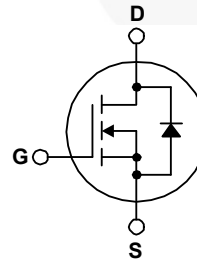
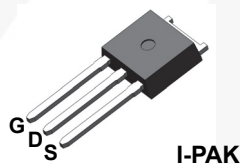
500 V, 2.5 A, 2.5 Ω

### Description

This N-Channel enhancement mode power MOSFET is produced using Fairchild Semiconductor's proprietary planar stripe and DMOS technology. This advanced MOSFET technology has been especially tailored to reduce on-state resistance, and to provide superior switching performance and high avalanche energy strength. These devices are suitable for switched mode power supplies, active power factor correction (PFC), and electronic lamp ballasts.

### Features

- 2.5 A, 500 V,  $R_{DS(on)} = 2.5 \Omega$  (Max.) @  $V_{GS} = 10 \text{ V}$ ,  $I_D = 1.25 \text{ A}$
- Low Gate Charge (Typ. 10 nC)
- Low  $C_{rss}$  (Typ. 8.5 pF)
- 100% Avalanche Tested



### Absolute Maximum Ratings $T_C = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	FQU3N50CTU	Unit
$V_{DSS}$	Drain-Source Voltage	500	V
$I_D$	Drain Current - Continuous ( $T_C = 25^\circ\text{C}$ )	2.5	A
	Drain Current - Continuous ( $T_C = 100^\circ\text{C}$ )	1.5	A
$I_{DM}$	Drain Current - Pulsed (Note 1)	10	A
$V_{GSS}$	Gate-Source Voltage	$\pm 30$	V
$E_{AS}$	Single Pulsed Avalanche Energy (Note 2)	200	mJ
$I_{AR}$	Avalanche Current (Note 1)	2.5	A
$E_{AR}$	Repetitive Avalanche Energy (Note 1)	3.5	mJ
$dv/dt$	Peak Diode Recovery $dv/dt$ (Note 3)	4.5	V/ns
$P_D$	Power Dissipation ( $T_C = 25^\circ\text{C}$ )	35	W
	- Derate above $25^\circ\text{C}$	0.28	W/ $^\circ\text{C}$
$T_J, T_{STG}$	Operating and Storage Temperature Range	-55 to +150	$^\circ\text{C}$
$T_L$	Maximum lead temperature for soldering, 1/8" from case for 5 seconds	300	$^\circ\text{C}$

### Thermal Characteristics

Symbol	Parameter	FQU3N50CTU	Unit
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case, Max.	3.5	$^\circ\text{C}/\text{W}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient (Minimum Pad of 2-oz Copper), Max.	110	$^\circ\text{C}/\text{W}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient (*1 in2 Pad of 2-oz Copper), Max.	50	$^\circ\text{C}/\text{W}$

## Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FQU3N50CTU	FQU3N50C	IPAK	Tube	N/A	N/A	75 units

## Electrical Characteristics T<sub>C</sub> = 25°C unless otherwise noted.

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit	
<b>Off Characteristics</b>							
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0 V, I <sub>D</sub> = 250 μA	500	--	--	V	
ΔBV <sub>DSS</sub> / ΔT <sub>J</sub>	Breakdown Voltage Temperature Coefficient	I <sub>D</sub> = 250 μA, Referenced to 25°C	--	0.7	--	V/°C	
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 500 V, V <sub>GS</sub> = 0 V	--	--	1	μA	
		V <sub>DS</sub> = 400 V, T <sub>C</sub> = 125°C	--	--	10	μA	
I <sub>GSSF</sub>	Gate-Body Leakage Current, Forward	V <sub>GS</sub> = 30 V, V <sub>DS</sub> = 0 V	--	--	100	nA	
I <sub>GSSR</sub>	Gate-Body Leakage Current, Reverse	V <sub>GS</sub> = -30 V, V <sub>DS</sub> = 0 V	--	--	-100	nA	
<b>On Characteristics</b>							
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 250 μA	2.0	--	4.0	V	
R <sub>DS(on)</sub>	Static Drain-Source On-Resistance	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 1.25 A	--	2.1	2.5	Ω	
g <sub>FS</sub>	Forward Transconductance	V <sub>DS</sub> = 40 V, I <sub>D</sub> = 1.25 A	--	1.5	--	S	
<b>Dynamic Characteristics</b>							
C <sub>iss</sub>	Input Capacitance	V <sub>DS</sub> = 25 V, V <sub>GS</sub> = 0 V, f = 1.0 MHz	--	280	365	pF	
C <sub>oss</sub>	Output Capacitance		--	50	65	pF	
C <sub>rss</sub>	Reverse Transfer Capacitance		--	8.5	11	pF	
<b>Switching Characteristics</b>							
t <sub>d(on)</sub>	Turn-On Delay Time	V <sub>DD</sub> = 250 V, I <sub>D</sub> = 2.5 A, R <sub>G</sub> = 25 Ω	--	10	30	ns	
t <sub>r</sub>	Turn-On Rise Time		--	25	60	ns	
t <sub>d(off)</sub>	Turn-Off Delay Time		(Note 4)	--	35	80	ns
t <sub>f</sub>	Turn-Off Fall Time		(Note 4)	--	25	60	ns
Q <sub>g</sub>	Total Gate Charge	V <sub>DS</sub> = 400 V, I <sub>D</sub> = 2.5 A, V <sub>GS</sub> = 10 V	--	10	13	nC	
Q <sub>gs</sub>	Gate-Source Charge		(Note 4)	--	1.5	--	nC
Q <sub>gd</sub>	Gate-Drain Charge		(Note 4)	--	5.5	--	nC
<b>Drain-Source Diode Characteristics and Maximum Ratings</b>							
I <sub>S</sub>	Maximum Continuous Drain-Source Diode Forward Current		--	--	2.5	A	
I <sub>SM</sub>	Maximum Pulsed Drain-Source Diode Forward Current		--	--	10	A	
V <sub>SD</sub>	Drain-Source Diode Forward Voltage	V <sub>GS</sub> = 0 V, I <sub>S</sub> = 2.5 A	--	--	1.4	V	
t <sub>rr</sub>	Reverse Recovery Time	V <sub>GS</sub> = 0 V, I <sub>S</sub> = 3 A, dI <sub>F</sub> / dt = 100 A/μs	--	170	--	ns	
Q <sub>rr</sub>	Reverse Recovery Charge		--	0.7	--	μC	

### NOTES:

1. Repetitive rating : pulse-width limited by maximum junction temperature.
2. L = 58 mH, I<sub>AS</sub> = 2.5 A, V<sub>DD</sub> = 50 V, R<sub>G</sub> = 25 Ω, starting T<sub>J</sub> = 25°C.
3. I<sub>SD</sub> ≤ 2.5 A, di/dt ≤ 200 A/μs, V<sub>DD</sub> ≤ BV<sub>DSS</sub>, starting T<sub>J</sub> = 25°C.
4. Essentially independent of operating temperature.

## Typical Performance Characteristics

Figure 1. On-Region Characteristics

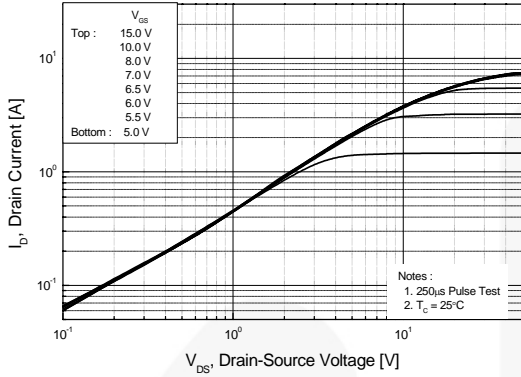


Figure 2. Transfer Characteristics

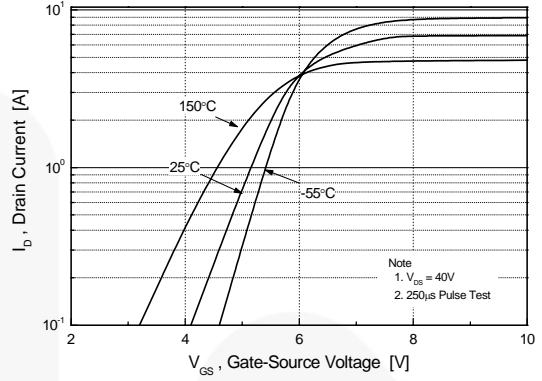


Figure 3. On-Resistance Variation vs. Drain Current and Gate Voltage

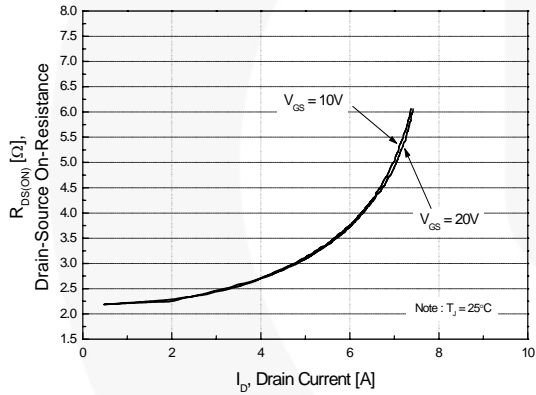


Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperature

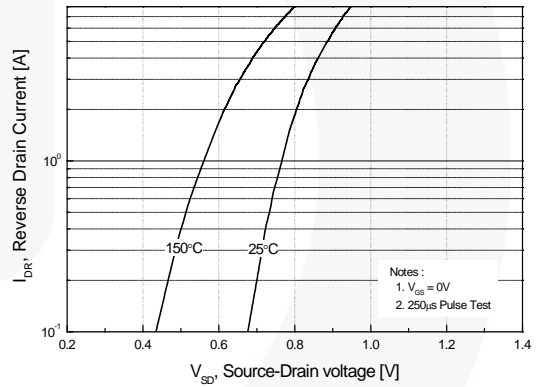


Figure 5. Capacitance Characteristics

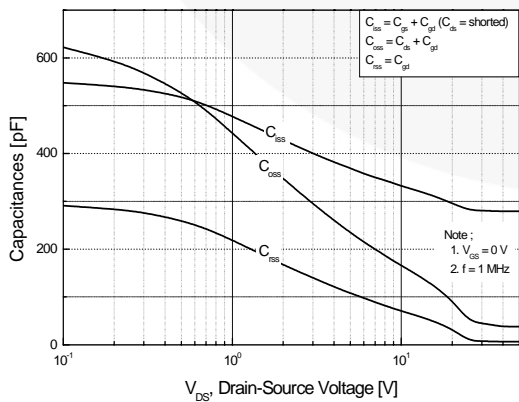
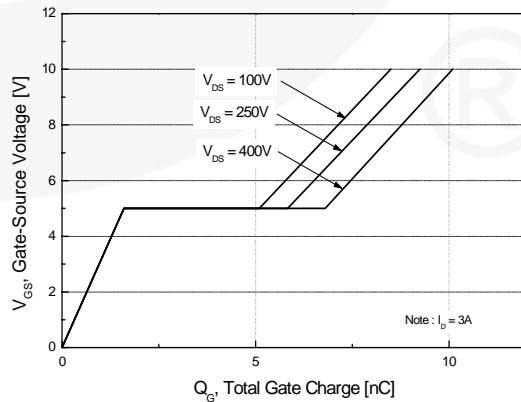


Figure 6. Gate Charge Characteristics



Typical Performance Characteristics (Continued)

Figure 7. Breakdown Voltage Variation vs. Temperature

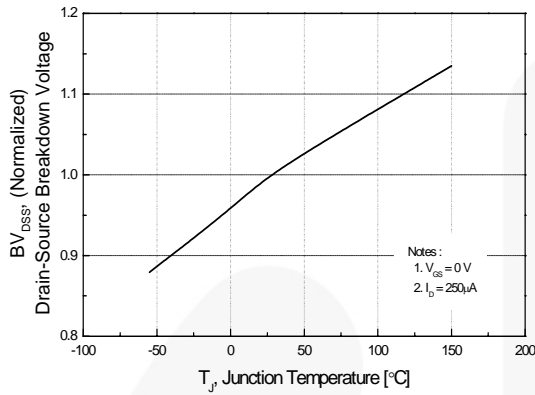


Figure 8. On-Resistance Variation vs. Temperature

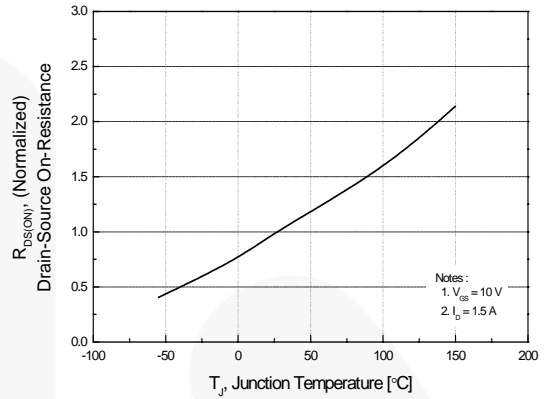


Figure 9. Maximum Safe Operating Area

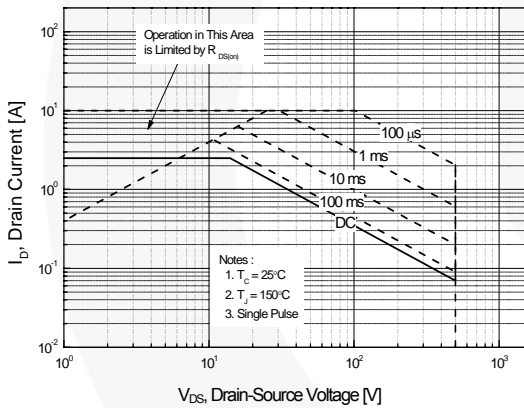


Figure 10. Maximum Drain Current vs. Case Temperature

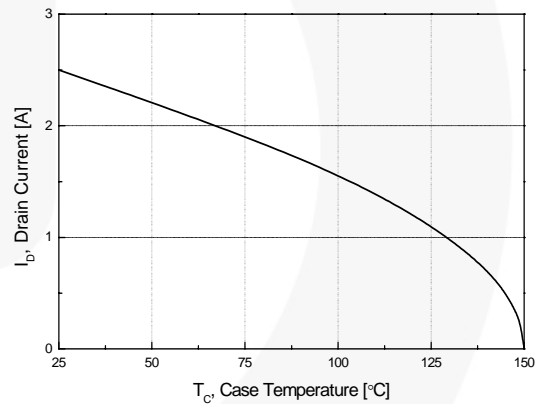
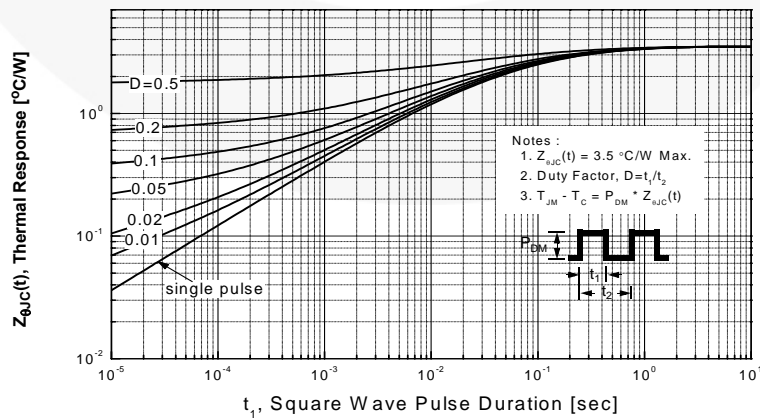


Figure 11. Transient Thermal Response Curve



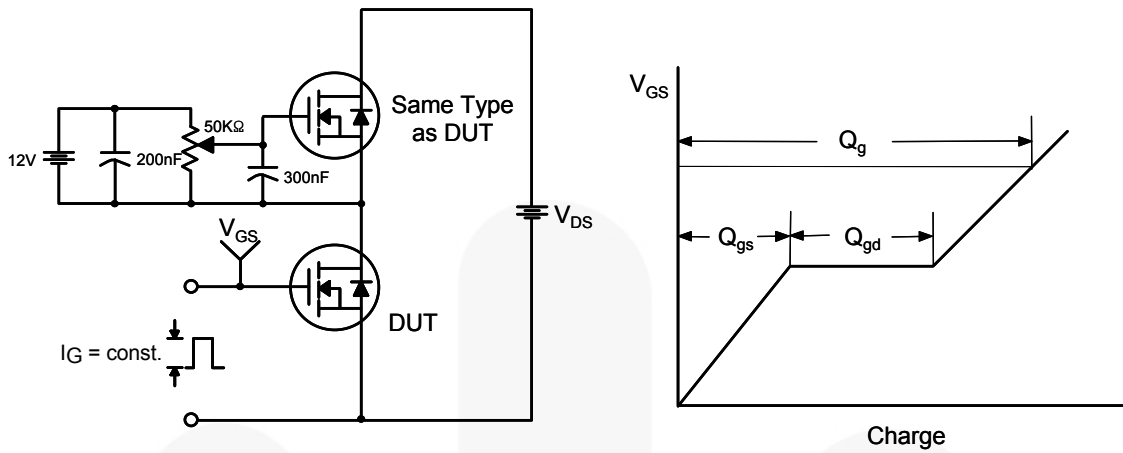


Figure 12. Gate Charge Test Circuit & Waveform



Figure 13. Resistive Switching Test Circuit & Waveforms

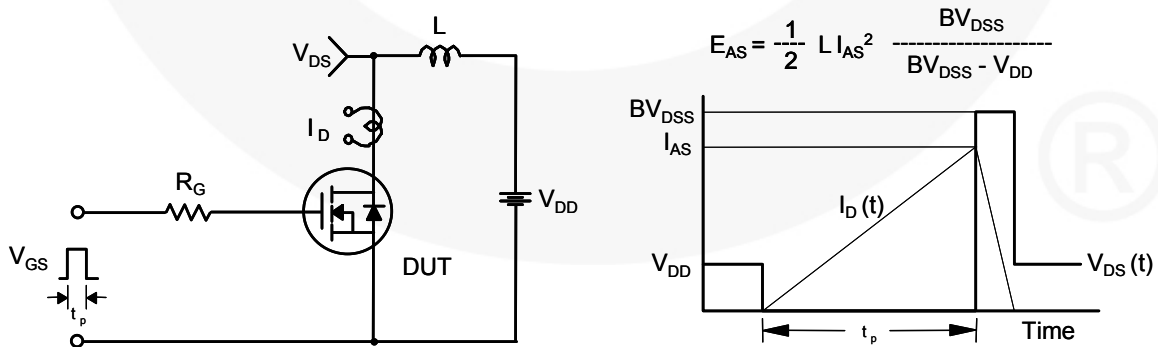


Figure 14. Unclamped Inductive Switching Test Circuit & Waveforms

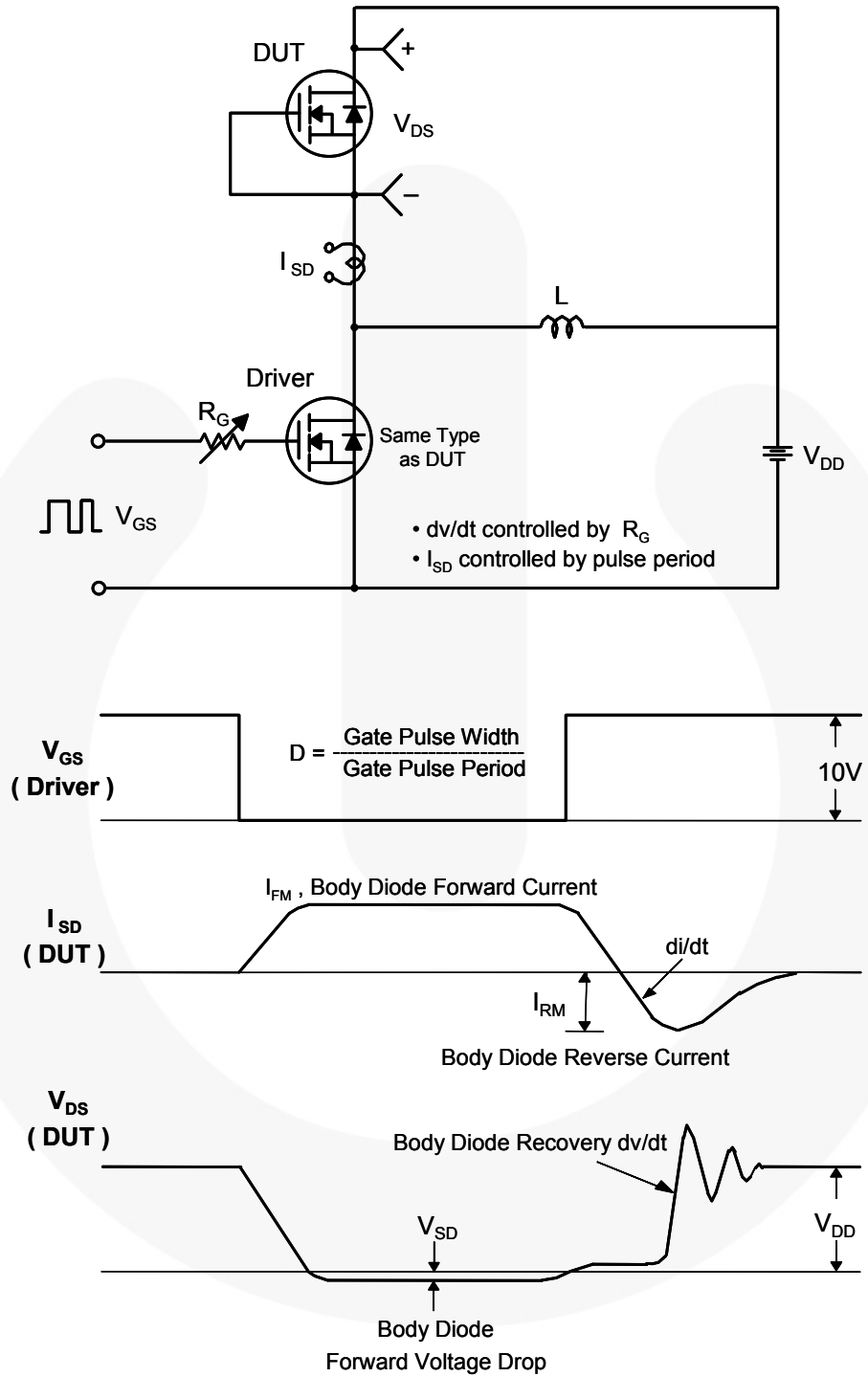
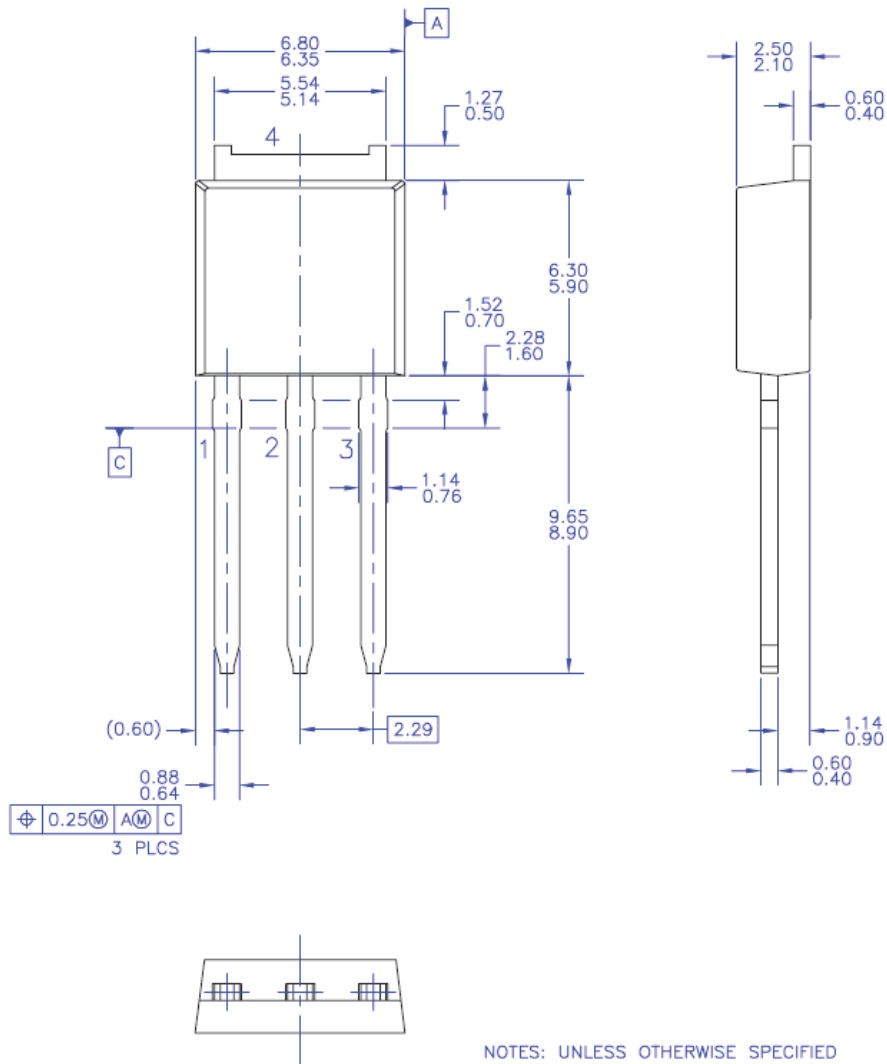


Figure 15. Peak Diode Recovery  $dv/dt$  Test Circuit & Waveforms

**Mechanical Dimensions**



**Figure 16. TO-251 (I-PAK), Molded, 3-Lead, Option AA**

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